

L Number	Hits	Search Text	DB	Time stamp
1	1148127	esd electrostatic discharge	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/03 16:03
2	493370	cmos ((bi complimentary) with (cmosmos))(functional with core) bicmos cmos (digital with (processor signal))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/03 16:07
3	12888	(esd electrostatic discharge) and (cmos ((bi complimentary) with (cmosmos))(functional with core) bicmos cmos (digital with (processor signal))) and buffer	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/03 16:07
4	6818	((esd electrostatic discharge) and (cmos ((bi complimentary) with (cmosmos))(functional with core) bicmos cmos (digital with (processor signal))) and buffer) and (substrate board)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/03 16:11
5	4986	((esd electrostatic discharge) and (cmos ((bi complimentary) with (cmosmos))(functional with core) bicmos cmos (digital with (processor signal))) and buffer) and (substrate board)) and ((i input) adj8 (o output))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/03 16:09
6	1753	((esd electrostatic discharge) and (cmos ((bi complimentary) with (cmosmos))(functional with core) bicmos cmos (digital with (processor signal))) and buffer) and (substrate board)) and ((i input) adj8 (o output))) and (pad (bond adj3 pad))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/03 16:09